TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX240F,TC74LCX240FW,TC74LCX240FT

Low-Voltage Octal Bus Buffer (inverted) with 5-V Tolerant Inputs and Outputs

The TC74LCX240F/FW/FT is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

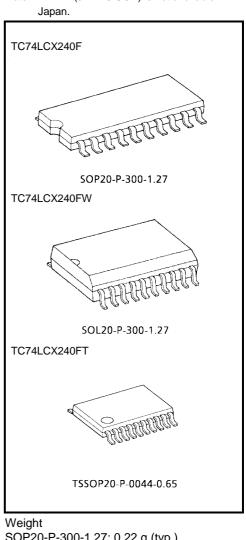
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

The 74LCX240F/FW/FT is an inverting 3-state buffer having two active-low output enables. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

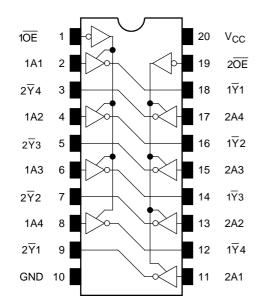
- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns} (\text{max}) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$ •
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\min) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 240 type



SOP20-P-300-1.27: 0.22 g (typ.) SOL20-P-300-1.27: 0.46 g (typ.) TSSOP20-P-0044-0.65: 0.08 g (typ.)

Note: xxxFW (JEDEC SOP) is not available in

Pin Assignment (top view)



Truth Table

| Inp | uts | Outputs | |
|-----|----------------|---------|--|
| ŌĒ | A _n | Outputs | |
| L | L | Н | |
| L | Н | L | |
| Н | Х | Z | |

X: Don't care

Z: High impedance

Maximum Ratings

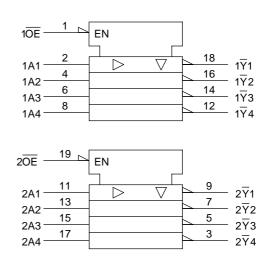
| Characteristics | Symbol | Rating | Unit |
|------------------------------------|-----------------------------------|-------------------------------|------|
| Power supply voltage | V _{CC} | -0.5 to 7.0 | V |
| DC input voltage | V _{IN} | -0.5 to 7.0 | V |
| | | -0.5 to 7.0 (Note 1) | |
| DC output voltage | Vout | -0.5 to V _{CC} + 0.5 | V |
| | | (Note 2) | |
| Input diode current | l _{IK} | -50 | mA |
| Output diode current | I _{ОК} | ±50 (Note 3) | mA |
| DC output current | I _{OUT} | ±50 | mA |
| Power dissipation | PD | 180 | mW |
| DC V _{CC} /ground current | I _{CC} /I _{GND} | ±100 | mA |
| Storage temperature | T _{stg} | –65 to 150 ° | |

Note 1: Output in OFF state

Note 2: High or low state. IOUT absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND, V_{OUT} > V_{CC}$

IEC Logic Symbol



Recommended Operating Conditions

| Characteristics | Symbol | Rating | Unit | |
|--------------------------|------------------|-------------------------------|------|--|
| Power supply voltage | 2.0 to 3.6 | | V | |
| i ower supply voltage | Vcc | 1.5 to 3.6 (Note 4) | v | |
| Input voltage | V _{IN} | 0 to 5.5 | V | |
| Output voltage | No | 0 to 5.5 (Note 5) | V | |
| Output voltage | Vout | 0 to V _{CC} (Note 6) | | |
| Output current | Іон/Іог | ±24 (Note 7) | mA | |
| Output current | IOH/IOL | ±12 (Note 8) | ma | |
| Operating temperature | T _{opr} | -40 to 85 | °C | |
| Input rise and fall time | dt/dv | 0 to 10 (Note 9) | ns/V | |

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: High or low state

Note 7: $V_{CC} = 3.0$ to 3.6 V

Note 8: $V_{CC} = 2.7$ to 3.0 V

Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

| Character | ristics | Symbol | Test Condition | | V _{CC} (V) | Min | Max | Unit | |
|---------------------------------|------------------------------|--|--|---------------------------|-------------------------|--------------------------|-------|------|--|
| | H-level | VIH | - | | 2.7 to 3.6 | 2.0 | | | |
| Input voltage | L-level | VIL | - | | 2.7 to 3.6 | _ | 0.8 | V | |
| | | | | I _{OH} = -100 μA | 2.7 to 3.6 | V _{CC} - 0.2 | | | |
| | H-level | V _{OH} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | $I_{OH} = -12 \text{ mA}$ | 2.7 | 2.2 | | | |
| | | _ | | I _{OH} = -18 mA | 3.0 | 2.4 | | | |
| Output voltage | | | | I _{OH} = -24 mA | 3.0 | 2.2 | | V | |
| | | | | I _{OL} = 100 μA | 2.7 to 3.6 | | 0.2 | | |
| | N | | I _{OL} = 12 mA | 2.7 | | 0.4 | | | |
| | L-level | V_{OL} $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 16 \text{ mA}$ | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | VIN = VIH OL VIL | I _{OL} = 16 mA | 3.0 | | 0.4 | |
| | | | | I _{OL} = 24 mA | 3.0 | | 0.55 | | |
| Input leakage currer | nt | I _{IN} | V _{IN} = 0 to 5.5 V | | 2.7 to 3.6 | | ±5.0 | μA | |
| | ate output OFF state current | | V _{IN} = V _{IH} or V _{IL} | | 2.7 to 3.6 | | 15.0 | | |
| 3-State Output OFF | state current | I _{OZ} | $V_{OUT} = 0$ to 5.5 V | | 2.7 10 3.0 | _ | ±5.0 | μA | |
| Power-off leakage c | urrent | I _{OFF} | $V_{IN}/V_{OUT} = 5.5 V$ | | 0 | _ | 10.0 | μA | |
| Quiescent supply current | | | $V_{IN} = V_{CC}$ or GND | | 2.7 to 3.6 | _ | 10.0 | | |
| | | Icc | $V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$ | | 2.7 to 3.6 | | ±10.0 | μA | |
| Increase in I _{CC} per | input | Δlcc | $V_{IH} = V_{CC} - 0.6 V$ | | 2.7 to 3.6 | | 500 | | |

AC Characteristics (Ta = -40 to 85°C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Min | Max | Unit |
|-------------------------|-------------------|--------------------|-------------------------------|-----|-----|------|
| Propagation delay time | t _{pLH} | Figure 1, Figure 2 | 2.7 | _ | 7.5 | ns |
| r lopagation dolay time | t _{pHL} | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 6.5 | 110 |
| Output enable time | t _{pZL} | Figure 1, Figure 3 | 2.7 | | 9.0 | ns |
| | t _{pZH} | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 8.0 | |
| Output disable time | t _{pLZ} | Figure 1, Figure 3 | 2.7 | | 8.0 | ns |
| | t _{pHZ} | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 7.0 | 115 |
| Output to output skew | t _{osLH} | _H (Note 10) | 2.7 | _ | _ | 00 |
| | t _{osHL} | | $\textbf{3.3}\pm\textbf{0.3}$ | | 1.0 | ns |

Note 10: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|---|------------------|--|---------------------|------|------|
| Quiet output maximum dynamic V _{OL} | V _{OLP} | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ | 3.3 | 0.8 | V |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | $V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ | 3.3 | 0.8 | V |

Capacitive Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|-------------------------------|------------------|----------------------------------|---------------------|------|------|
| Input capacitance | C _{IN} | _ | 3.3 | 7 | pF |
| Output capacitance | C _{OUT} | | 3.3 | 8 | pF |
| Power dissipation capacitance | C _{PD} | f _{IN} = 10 MHz (Note 1 | 1) 3.3 | 25 | pF |

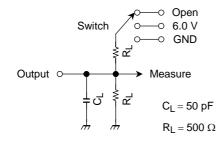
Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per bit)$

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AC Test Circuit



| Parameter | Switch |
|-------------------------------------|--------|
| t _{pLH} , t _{pHL} | Open |
| t _{pLZ} , t _{pZL} | 6.0 V |
| t _{pHZ} , t _{pZH} | GND |



AC Waveform

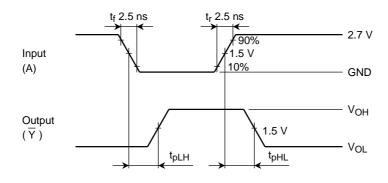


Figure 2 t_{pLH}, t_{pHL}

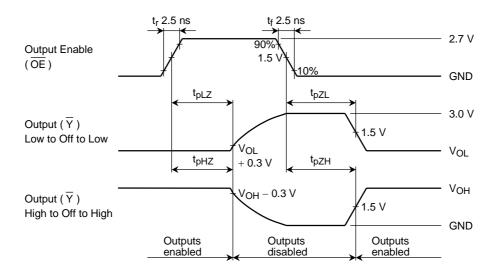
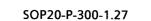
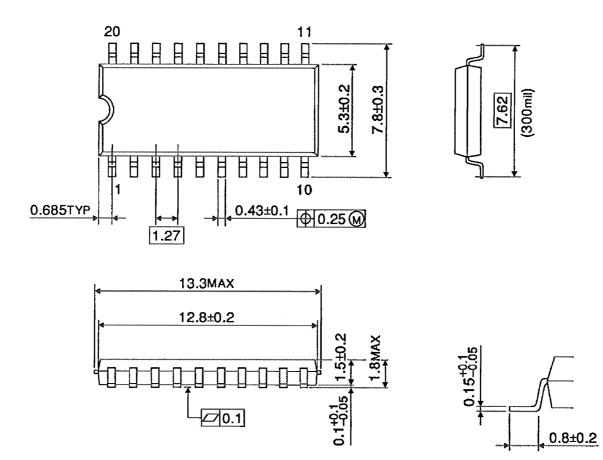


Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

Package Dimensions



Unit : mm

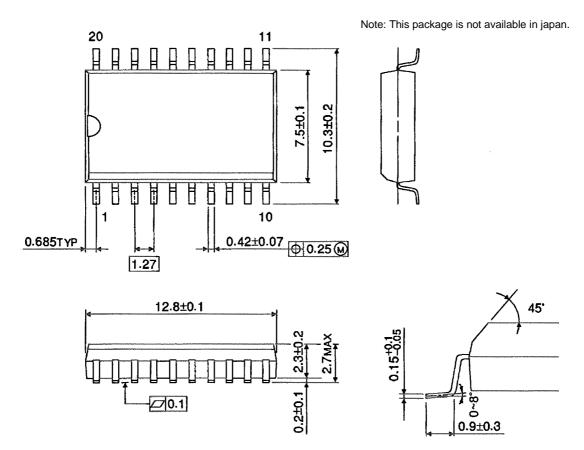


Weight: 0.22 g (typ.)

Package Dimensions

SOL20-P-300-1.27

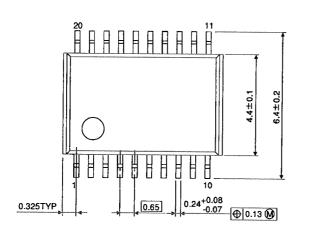
Unit : mm



Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65



6.75MAX

6.5±0.1

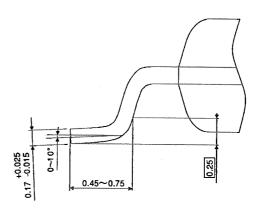
- 🔲 0.1

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1.0±0.05 1.2MAX

0.1±0.05

Unit : mm



Weight: 0.08 g (typ.)

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